



S E M I C O N D U C T O R

SR820 THRU SR8A0(SINGLE CHIP)

SCHOTTKY BARRIER RECTIFIER
Reverse Voltage - 20 to 100 Volts
Forward Current - 8.0Amperes

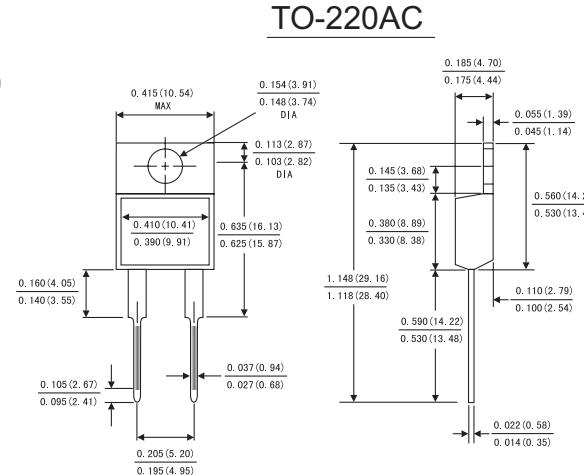
FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- Single rectifier construction
- High surge capability
- For use in low voltage ,high frequency inverters,
free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:250 °C/10 seconds,
0.25"(6.35mm)from case



MECHANICAL DATA

- Case: JEDEC TO-220AC molded plastic body
- Terminals: Lead solderable per MIL-STD-750,method 2026
- Polarity: As marked
- Mounting Position: Any
- Weight: 0.08ounce, 2.24 grams



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

	Symbols	SR 820	SR 830	SR 840	SR 850	SR 860	SR 880	SR 8A0	Units
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	Volts
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	57	71	Volts
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	Volts
Maximum average forward rectified current (see Fig.1)	I _(AV)						8.0		Amps
Repetitive peak forward current(square wave, 20KHZ) at T _c =105°C	I _{FRM}						16.0		Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}						150.0		Amps
Maximum instantaneous forward voltage at 8.0 A(Note 1)	V _F		0.65		0.75	0.80	0.85		Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	I _R	T _A =25°C T _A =125°C			1.0				mA
			15			50			
Typical thermal resistance (Note 2)	R _{θJC}			2.5					°C/W
Operating junction temperature range	T _J		-65 to +125			-65 to +150			°C
Storage temperature range	T _{STG}			-65 to +150					°C

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Thermal resistance from junction to case

RATINGS AND CHARACTERISTIC CURVES SR820-SR8AO(SINGLE CHIP)

FIG.1-FORWARD CURRENT DERATING CURVE

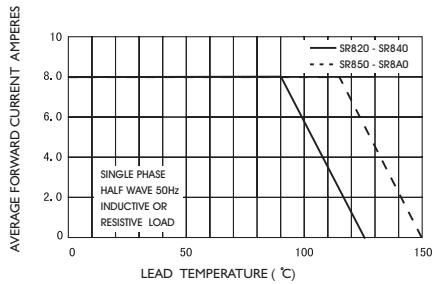


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

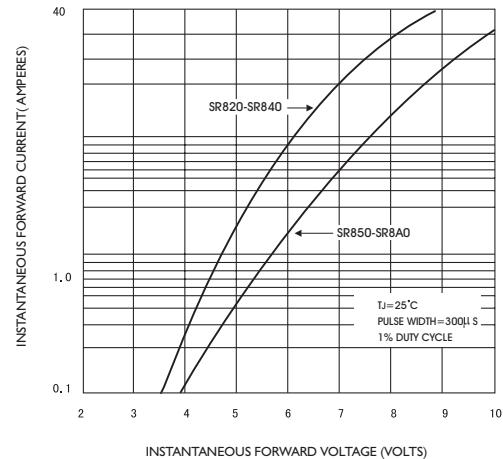


FIG.4-TYPICAL JUNCTION CAPACITANCE

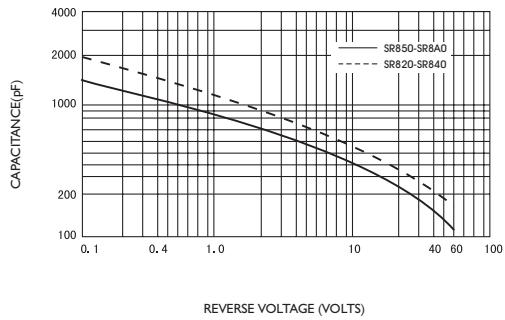


FIG.5-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

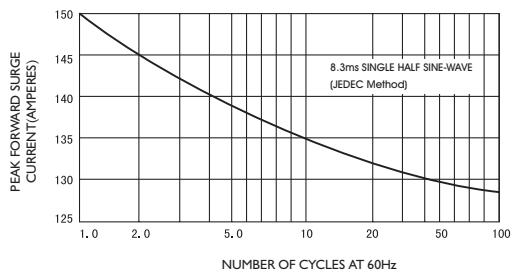


FIG.3-TYPICAL REVERSE CHARACTERISTICS

